



Digital transistors (built-in resistors)

DTA123JE/DTA123JUA

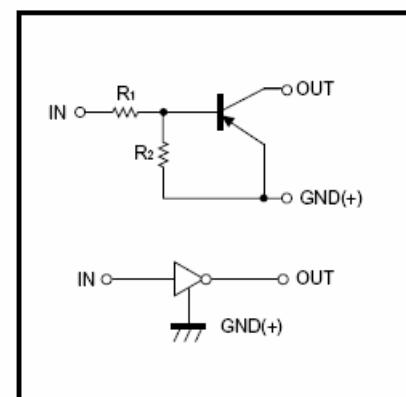
DTA123JKA/DTA123JCA / DTA123JSA

DIGITAL TRANSISTOR (PNP)

FEATURES

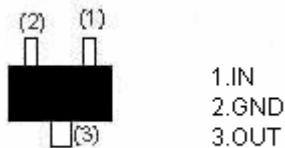
- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit)
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects
- 3) Only the on/off conditions need to be set for operation, making device design easy

● Equivalent circuit



PIN CONNECTIONS AND MARKING

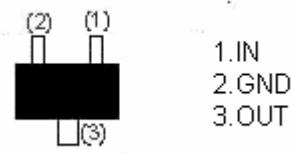
DTA123JE



SOT-523

Addreviated symbol: E32

DTA123JUA



SOT-323

Addreviated symbol: 132

DTA123JKA



SOT-23-3L

Addreviated symbol: E32

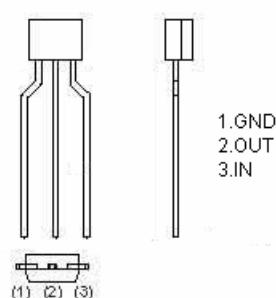
DTA123JCA



SOT-23

Addreviated symbol: E32

DTA123JSA



TO-92S

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTA123J□)					Unit				
		E	UA	KA	CA	SA					
Supply voltage	V _{CC}	-50					V				
Input voltage	V _{IN}	-12~+5					V				
Output current	I _O	-100					mA				
	I _{C(MAX)}	-100									
Power dissipation	P _d	150	200		300		mW				
Junction temperature	T _j	150					°C				
Storage temperature	T _{stg}	-55~150					°C				

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Input voltage	V _{I(off)}	-0.5			V	V _{CC} =-5V, I _O =-100μA
	V _{I(on)}			-1.1		V _O =-0.3V, I _O =-5mA
Output voltage	V _{O(on)}		-0.1	-0.3	V	I _O /I _I =-5mA/-0.25mA
Input current	I _I			-3.6	mA	V _I =-5V
Output current	I _{O(off)}			-0.5	μA	V _{CC} =-50V, V _I =0
DC current gain	G _I	80				V _O =-5V, I _O =-10mA
Input resistance	R ₁	1.54	2.2	2.86	KΩ	-
Resistance ratio	R ₂ /R ₁	17	21	26		-
Transition frequency	f _T		250		MHz	V _O =-10V, I _O =-5mA, f=100MHz